



DMN3150L

N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

Low On-Resistance:

$$\begin{split} R_{DS(ON)} < 54 m \Omega & @ V_{GS} = 10V \\ R_{DS(ON)} < 72 m \Omega & @ V_{GS} = 4.5V \\ R_{DS(ON)} < 115 m \Omega & W_{GS} = 2.5V \end{split}$$

- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 2)
- "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

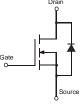
• Case: SOT-23

- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)

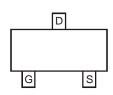
SOT-23







EQUIVALENT CIRCUIT



Pin Configuration

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Drain Source Voltage		V _{DSS}	30	V
Gate-Source Voltage		V _{GSS}	±12	V
Drain Current (Note 1)	$T_A = 25$ °C $T_A = 70$ °C	I _D	3.8 3.1	Α
Drain Current (Note 1)	Pulsed	I _{DM}	15	Α
Body-Diode Continuous Current (Note 1)		I _S	2.0	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	P_{D}	1.4	W
Thermal Resistance, Junction to Ambient @T _A = 25°C (Note 1)	$R_{ hetaJA}$	90	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

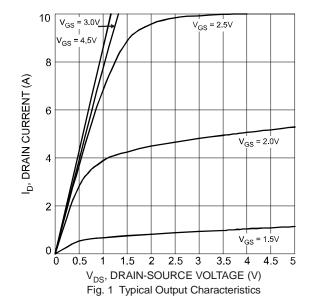


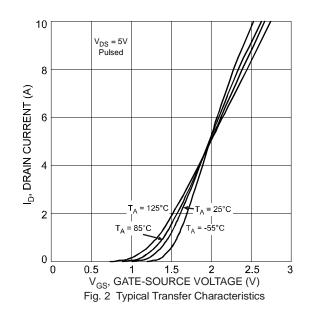
Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 4)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	800	nA	$V_{DS} = 28V, V_{GS} = 0V$	
Gate-Body Leakage	loos	_	_	±80	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
, ,	I _{GSS}			±800		$V_{GS} = \pm 19V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage	V _{GS(th)}	0.62	0.92	1.4	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
			39	54		$V_{GS} = 10V, I_D = 3.8A$	
Static Drain-Source On-Resistance	R _{DS (ON)}	_	52	72	$m\Omega$	$V_{GS} = 4.5V, I_D = 3.6A$	
		_	90	115		$V_{GS} = 2.5V, I_D = 3.1A$	
Forward Transconductance	Y _{fs}	_	3	_	S	$V_{DS} = 5V, I_{D} = 3.1A$	
Source-Drain Diode Forward Voltage	V_{SD}	_	_	1.16	V	$V_{GS} = 0V, I_S = 2.0A$	
DYNAMIC CHARACTERISTICS	•		•	-		•	
Gate Resistance	R_g	-	4.17	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, f = 1MHz	
Total Gate Charge (10V)	Qg	-	8.2	-	nC	$V_{GS} = 10 \text{ V}, V_{DS} = 10 \text{V},$ $I_{D} = 3.8 \text{ A}$	
Total Gate Charge (4.5V)	Qg	-	3.7	-	nC	V 45.V.V 40.V	
Gate-Source Charge	Q_{gs}	-	0.7	-	nC	$V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V},$	
Gate-Drain Charge	Q_{gd}	-	1.1	-	nC	$I_D = 3.8 \text{ A}$	
Turn-On Delay Time	t _{D(on)}	-	1.14	-	ns		
Turn-On Rise Time	tr	-	3.49	1	ns	$V_{DD} = 15V, V_{GEN} = 10V,$	
Turn-Off Delay Time	t _{D(off)}	-	15.02	-	ns	$R_{GEN} = 6\Omega$, $R_L = 3.9\Omega$	
Turn-Off Fall Time	t _f	-	3.26	-	ns		
Input Capacitance	C _{iss}	_	305	_	pF	., 5,,,,	
Output Capacitance	Coss	_	74		pF	$V_{DS} = 5V, V_{GS} = 0V$ - f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	48	_	рF	I — I.UIVII IZ	

Notes:

- 1. Device mounted on FR-4 PCB. t ≤5 sec.
- No purposefully added lead.
 Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 Short duration pulse test used to minimize self-heating effect.







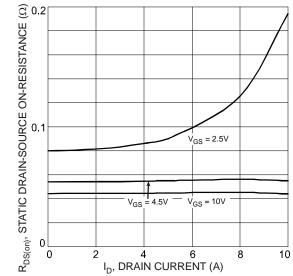


Fig. 3 On-Resistance vs. Drain Current and Gate Voltage

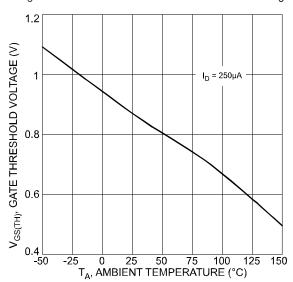


Fig. 5 Gate Threshold Voltage vs. Ambient Temperature

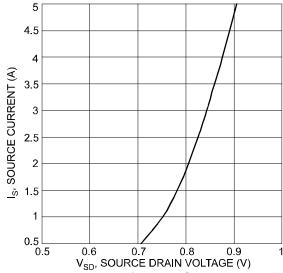


Fig. 7 Reverse Drain Current vs. Source-Drain Voltage

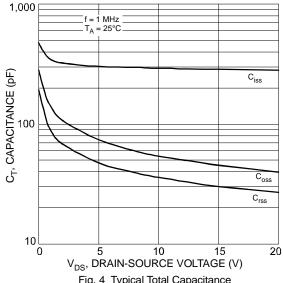


Fig. 4 Typical Total Capacitance

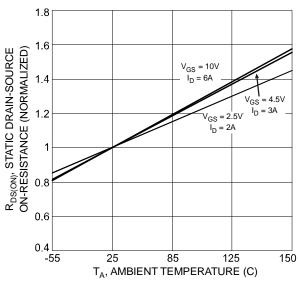


Fig. 6 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature

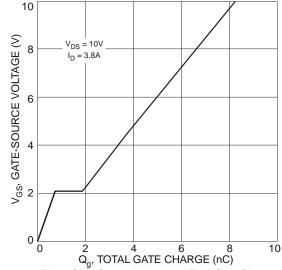


Fig. 8 Gate-Source Voltage vs. Total Gate Charge

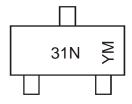


Ordering Information (Note 5)

Part Numb	oer	Case	Packaging
DMN3150I	7	SOT-23	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

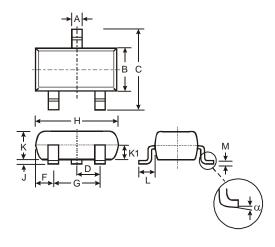


31N = Product Type Marking Code YM = Date Code Marking Y = Year (ex: T = 2006) M = Month (ex: 9 = September)

Date Code Key

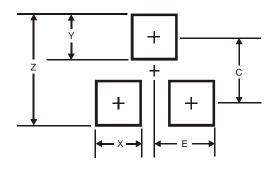
Year	200	6	2007		2008	20	09	2010		2011	2	2012
Code	Т		U		V	V	V	Χ		Υ		Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Package Outline Dimensions



SOT-23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.903	1.10	1.00			
K1	-	-	0.400			
L	0.45	0.61	0.55			
M	0.085	0.18	0.11			
α	0°	8°	-			
All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Υ	0.9
С	2.0
E	1.35



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